

Casimir forces and graphene sheets

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The Casimir force between two infinitely thin parallel sheets in a setting of N such sheets is found. The finite two-dimensional conductivities, which describe the dispersive and absorptive properties of each sheet, are taken into account, whereupon the theory is applied to interacting graphenes. By exploring similarities with in-plane optical spectra for graphite, the conductivity of graphene is modeled as a combination of Lorentz-type oscillators. We find that the graphene transparency and the existence of a universal constant conductivity $e^2/(4\hbar)$ result in the graphene/graphene Casimir interaction at large separations to have the same distance dependence as the one for perfect conductors but with much smaller magnitude. The Casimir force is also studied when the graphene system is above a substrate or immersed in a medium. It is found that the response properties of the environmental materials can strongly affect the graphene interaction.

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I. INTRODUCTION

The Casimir force is a fundamental quantum-mechanical relativistic phenomenon, which originates from the vacuum fluctuations of the electromagnetic field. It couples electrically neutral objects with or without permanent electric and/or magnetic moments. In the case of two perfectly conducting infinite plates, the Casimir force depends only on the distance and two fundamental constants: Planck's constant and the speed of light.^{1,2}

The Casimir force is of particular interest at the nanoscale. It has been shown that such a force is responsible for limiting the operation of many nanostructured devices, such as nanoelectrical-mechanical and microelectrical-mechanical systems by causing striction, friction, or adhesion.^{3,4} This has motivated devising experiments to detect the effect in various structures. Sophisticated techniques using torsional pendulum or atomic force microscope have been used to measure the Casimir force between metallic and dielectric surfaces with high accuracy.^{5,6} The stability of many nanostructured materials, related devices, and experimental settings has also been connected to dispersion forces originating from the Casimir effect. Graphitic nanostructures, such as graphenes (a single layer of graphite is graphene), carbon nanotubes (cylindrically rolled concentric graphenes), and graphene nanoribbons (finite width graphenes) are particular examples.^{7,8}

Recently, single layers of graphite have been isolated using micromechanical cleavage.^{9,10} At present, graphene is one of the most interesting and most studied materials and has paved the way for future carbon-based electronics. Many applications of graphene rely on the ability to continuously tune its charge carrier density and mobility.¹¹ This has allowed the development of new transistors operating at high frequencies.¹² Other applications are also very promising. Nanomechanical resonators, for example, are especially attractive due to their mechanical stability and high resonant frequency.¹³

Isolated graphenes also raise the possibility of studying the Casimir force between essentially two-dimensional structures with peculiar dielectric response properties and thereby

uncovering further insights into the nature of the Casimir interaction. In addition, graphene/graphene or graphene/substrate mutual interactions are important components of many experimental settings. The Casimir force can be calculated using the Lifshitz theory, which takes into account the macroscopic dielectric response of the objects.¹⁴ This theory was adapted for the case of two graphene sheets using an idealistic description of the dielectric permittivity by assuming a Drude-type model.¹⁵ Such an approximation, however, does not take into account the electronic properties specific to graphene. Researchers have also considered the Casimir interaction between a graphene and a perfect conductor within a quantum field theory approach by using a more realistic representation of the graphene dielectric response,¹⁶ where low-momentum electrons were described via the Dirac model.

The Casimir effects of one infinitely thin sheet,¹⁷ two sheets,¹⁸ and one infinitely thin sheet with a nearby charge¹⁹ have been studied previously in the context of a hydrodynamic model or plasma sheet model.²⁰ The goal of this work is to extend the theory to N parallel infinitely thin sheets at different separations and different environments, and to take into account the specific optical properties, characterized by the conductivity, of each separate sheet. The objective is to apply the results to the case of parallel graphenes in order to understand how the distance separation and peculiar characteristics of the graphene and environmental dispersion properties manifest in their mutual Casimir force. Our method utilizes a quantum electrodynamical approach based on linear response theory. An essential part is the explicit calculation of the dyadic Green's function for this system and the inclusion of the finite conductivity of the separate sheets.

The rest of the paper is organized as follows. In Sec. II, the electromagnetic field induced fluctuation stresses between two infinitely thin parallel plates is developed via linear response theory. In Sec. III, the dyadic Green's function for two sheets with frequency-dependent conductivities is found. In Sec. IV, the Casimir force between two parallel sheets within N sheets is characterized via recursion relationships for the reflection coefficients. Finally in Sec. V, the theory is applied to find the Casimir force between graphenes and be-

tween graphenes and a substrate. The conclusions are described in Sec. VI.

II. FLUCTUATION FORCES

In classical electrodynamics, the force is calculated using the Maxwell stress tensor for the electromagnetic pressure

$$\vec{T} = \frac{1}{4\pi} \left(\mathbf{E}\mathbf{E} - \frac{1}{2}E^2\vec{1} + \mathbf{B}\mathbf{B} - \frac{1}{2}B^2\vec{1} \right), \quad (1)$$

where \mathbf{E} and \mathbf{B} are the electric and magnetic fields, respectively, and $\vec{1}$ is the unit matrix. In order to present a formalism to find the Casimir stresses, we consider the radiation-matter interaction Hamiltonian within the dipole approximation described by

$$\delta H = - \int d^3r \delta \mathbf{P}(\mathbf{r}, t) \cdot \mathbf{E}(\mathbf{r}, t), \quad (2)$$

where \mathbf{P} is the polarization.

The quantum mechanical description is performed by simply substituting the classical fields with a symmetrized product²¹ of quantum-mechanical operators (denoted by hats in what follows). Then, using linear response theory,²² the perturbed electric fields due to an external polarization source field become

$$\delta \mathbf{E}(\mathbf{r}, t) = \int_{-\infty}^t dt' \int d^3r' \vec{G}(\mathbf{r}, \mathbf{r}', t-t') \cdot \delta \mathbf{P}(\mathbf{r}', t'), \quad (3)$$

$$\vec{G}(\mathbf{r}, \mathbf{r}', t-t') = \frac{i}{\hbar} \langle [\hat{\mathbf{E}}(\mathbf{r}, t), \hat{\mathbf{E}}(\mathbf{r}', t')] \rangle, \quad (4)$$

where $\langle \hat{O} \rangle = \text{Tr}(\hat{\rho} \hat{O})$, $\hat{\rho} = \exp([F_0 - \hat{H}_0]/k_B T)$ is the statistical matrix operator in the canonical ensemble, F_0 is the free energy, \hat{H}_0 is the unperturbed Hamiltonian, \vec{G} is the Dyadic Green's function, k_B is Boltzmann's constant, and T is the temperature. Note that $\vec{G}(\mathbf{r}, \mathbf{r}', t, t') = \vec{G}(\mathbf{r} - \mathbf{r}', t - t')$ from the homogeneity of space-time.

Define the structure functions \vec{S}_{EE} and \vec{S}_{BB} using Fourier transforms as follows:

$$\begin{aligned} & \frac{1}{2} \langle [\hat{\mathbf{E}}(\mathbf{r}, t) \hat{\mathbf{E}}(\mathbf{r}', t') + \hat{\mathbf{E}}(\mathbf{r}', t') \hat{\mathbf{E}}(\mathbf{r}, t)] \rangle \\ &= \int \frac{d\omega}{2\pi} \vec{S}_{EE}(\mathbf{r}, \mathbf{r}', \omega) e^{-i\omega(t-t')}, \\ & \frac{1}{2} \langle [\hat{\mathbf{B}}(\mathbf{r}, t) \hat{\mathbf{B}}(\mathbf{r}', t') + \hat{\mathbf{B}}(\mathbf{r}', t') \hat{\mathbf{B}}(\mathbf{r}, t)] \rangle \\ &= \int \frac{d\omega}{2\pi} \vec{S}_{BB}(\mathbf{r}, \mathbf{r}', \omega) e^{-i\omega(t-t')}. \end{aligned} \quad (5)$$

Then using the fluctuation dissipation theorem,^{23,24} one can express the structure function \vec{S}_{EE} in terms of the imaginary part of the frequency-dependent Green's function at finite temperature as

$$\vec{S}_{EE}(\mathbf{r}, \mathbf{r}', \omega) = \hbar \times \Im \vec{G}(\mathbf{r}, \mathbf{r}', \omega) \coth\left(\frac{\hbar\omega}{2k_B T}\right). \quad (6)$$

Similarly, the correlations in the magnetic field may be found from Faraday's law by taking the curl of the electric field. These are expressed in terms of the function \vec{S}_{BB} by

$$\vec{S}_{BB}(\mathbf{r}, \mathbf{r}', \omega) = \hbar \frac{c^2}{\omega^2} \Im \nabla \times \vec{G}(\mathbf{r}, \mathbf{r}', \omega) \times \nabla' \coth\left(\frac{\hbar\omega}{2k_B T}\right), \quad (7)$$

where $\times \nabla'$ is the curl taken on the Green's function with respect to the prime coordinates. Therefore, from Eqs. (1) and (5)–(7) the temperature-dependent quantum electromagnetic stress is found via the Green's function²⁵

$$\begin{aligned} \vec{T} &= \frac{1}{4\pi} \left(\vec{T}_1 + \vec{T}_2 - \frac{\vec{1}}{2} \text{Tr}[\vec{T}_1 + \vec{T}_2] \right), \\ \vec{T}_1 &= \lim_{\mathbf{r} \rightarrow \mathbf{r}'} \int \vec{S}_{EE}(\mathbf{r}, \mathbf{r}', \omega) \frac{d\omega}{2\pi}, \\ \vec{T}_2 &= \lim_{\mathbf{r} \rightarrow \mathbf{r}'} \int \vec{S}_{BB}(\mathbf{r}, \mathbf{r}', \omega) \frac{d\omega}{2\pi}. \end{aligned} \quad (8)$$

Finally, the identity $\coth(x) = \sum_{n=-\infty}^{\infty} \frac{x}{x^2 + n^2 \pi^2}$ allows one to obtain

$$\begin{aligned} \vec{T}_1 &= \lim_{\mathbf{r} \rightarrow \mathbf{r}'} k_B T \sum_{n=-\infty}^{\infty} \vec{G}(\mathbf{r}, \mathbf{r}', i\omega_n), \\ \vec{T}_2 &= \lim_{\mathbf{r} \rightarrow \mathbf{r}'} k_B T \sum_{n=-\infty}^{\infty} \frac{c^2}{(i\omega_n)^2} \nabla \times \vec{G}(\mathbf{r}, \mathbf{r}', i\omega_n) \times \nabla', \end{aligned} \quad (9)$$

where $\omega_n = 2\pi n k_B T / \hbar$ are the Matsubara frequencies.

III. GREEN'S FUNCTION FOR THREE LAYERS

In order to find the Casimir force from Eq. (8) for a specific structure, one needs to calculate the Green's function. The Green's function obeys the following equation:

$$\left[\nabla \times \nabla \times - \frac{\omega^2}{c^2} \right] \vec{G}(\mathbf{r}, \mathbf{r}', \omega) = 4\pi \frac{\omega^2}{c^2} \vec{1} \delta(\mathbf{r} - \mathbf{r}'), \quad (10)$$

which is found from the solution of Maxwell's equations.²⁶

The system under consideration consists of parallel, infinitely thin sheets located in a vacuum. Each sheet is positioned at the boundary between two adjacent layers, and it is specified by a two-dimensional, isotropic conductivity

$$\vec{\sigma}_{j,j+1} = \begin{pmatrix} \sigma_{j,j+1} & 0 & 0 \\ 0 & \sigma_{j,j+1} & 0 \\ 0 & 0 & 0 \end{pmatrix}, \quad (11)$$

where $j, j+1$ is the boundary between two adjacent layers. $\sigma_{j,j+1}$ accounts for the specific finite absorptive and dispersive optical properties of each sheet.

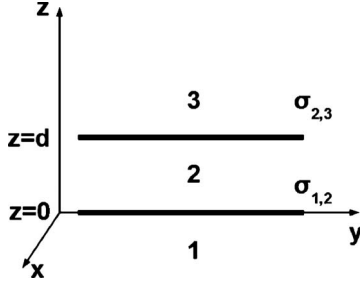


FIG. 1. The free space regions denoted as 1,2,3 separated by two infinitely thin sheets extending in the x - y plane and separated by a distance d in the z direction. The infinitely thin sheets are located at $z=0$ and $z=d$. The conductivities are also denoted.

In general, the Green's function may be split in two terms

$$\vec{G}^{lj} = \vec{G}_0^j + \vec{G}_s^{lj}, \quad (12)$$

where \vec{G}^{lj} is the Green's function in region l with a source in region j , \vec{G}_0^j is the free Green's function from a pointlike source placed in layer j without any boundaries, and \vec{G}_s^{lj} is the scattering Green's function in region l with a source in region j . The free Green's function is later dropped from the calculation of the stress tensor since the Casimir effect does not exist in homogeneous space.

The calculation of the force between planar sheets given in this work is based on a procedure using the generalized Fresnel reflection coefficients. The method involves the explicit form of the dyadic Green's function for a system of two parallel planar sheets.^{23,24} Thus we first calculate $\vec{G}(\mathbf{r}, \mathbf{r}', \omega)$ for the three-layer/two-sheet structure shown in Fig. 1.

Since the system has a planar geometry, we use the general dyadic form of \vec{G} in terms of the following orthogonal functions:^{27,28}

$$\mathbf{M}(\mathbf{k}) = \nabla \times [\hat{\mathbf{z}}\phi] \quad \text{and} \quad \mathbf{N}(\mathbf{k}) = \frac{1}{k} \nabla \times \mathbf{M}(\mathbf{k}), \quad (13)$$

where $\phi = \exp(i\mathbf{k} \cdot \mathbf{r})$ with \mathbf{k} being the wave vector of the electromagnetic excitations. These functions obey the orthogonality relations

$$\begin{aligned} \int dV \mathbf{M}(\mathbf{k}) \cdot \mathbf{N}(-\mathbf{k}') &= 0, \\ \int dV \mathbf{M}(\mathbf{k}) \cdot \mathbf{M}(-\mathbf{k}') &= (2\pi)^3 k_{\perp}^2 \delta(\mathbf{k} - \mathbf{k}'), \\ \int dV \mathbf{N}(\mathbf{k}) \cdot \mathbf{N}(-\mathbf{k}') &= (2\pi)^3 k_{\perp}^2 \delta(\mathbf{k} - \mathbf{k}'), \end{aligned} \quad (14)$$

where $k_{\perp}^2 = k_x^2 + k_y^2$ and the integration is carried over space. The bulk Green's function is found to be of the following form:

$$\begin{aligned} \vec{G}_0^j(\mathbf{r}, \mathbf{r}', \omega) &= -4\pi\delta(\mathbf{r} - \mathbf{r}')\mathbf{z}\mathbf{z} + \frac{i\omega^2}{c^2} \int \frac{dk_{\perp}^2}{2\pi k_{\perp}^2 h} \\ &\times [\mathbf{M}(h)\mathbf{M}'(-h) + \mathbf{N}(h)\mathbf{N}'(-h)], \\ &(z - z' > 0), \end{aligned} \quad (15)$$

$$\begin{aligned} \vec{G}_0^j(\mathbf{r}, \mathbf{r}', \omega) &= -4\pi\delta(\mathbf{r} - \mathbf{r}')\mathbf{z}\mathbf{z} + \frac{i\omega^2}{c^2} \int \frac{dk_{\perp}^2}{2\pi k_{\perp}^2 h} \\ &\times [\mathbf{M}(-h)\mathbf{M}'(h) + \mathbf{N}(-h)\mathbf{N}'(h)], \\ &(z - z' < 0), \end{aligned} \quad (16)$$

$$\mathbf{M}(h) = i(k_y\hat{\mathbf{x}} - k_x\hat{\mathbf{y}})e^{i(\mathbf{k}_{\perp} \cdot \mathbf{r}_{\perp} + hz)},$$

$$\mathbf{M}(-h) = i(k_y\hat{\mathbf{x}} - k_x\hat{\mathbf{y}})e^{i(\mathbf{k}_{\perp} \cdot \mathbf{r}_{\perp} - hz)},$$

$$\mathbf{M}'(-h) = -i(k_y\hat{\mathbf{x}} - k_x\hat{\mathbf{y}})e^{-i(\mathbf{k}_{\perp} \cdot \mathbf{r}_{\perp} + hz')},$$

$$\mathbf{M}'(h) = -i(k_y\hat{\mathbf{x}} - k_x\hat{\mathbf{y}})e^{-i(\mathbf{k}_{\perp} \cdot \mathbf{r}_{\perp} - hz')}, \quad (17)$$

where $h = \sqrt{\omega^2/c^2 - k_{\perp}^2}$ and $\mathbf{r}_{\perp} = x\hat{\mathbf{x}} + y\hat{\mathbf{y}}$. Similarly, $\mathbf{N}(\pm h)$, $\mathbf{N}'(\pm h)$ are defined via Eq. (13).

In this way, the bulk Green's function is expressed in terms of a linear combination of transverse electric (\mathbf{M} -term) and transverse magnetic (\mathbf{N} -term) modes. The scattering part of the Green's function is also sought in terms of the orthogonal functions \mathbf{M} and \mathbf{N} , and it is found from the boundary conditions for the tangential electric and magnetic fields across each plane.

The continuity of the electric field across each boundary from Fig. 1 is expressed as

$$\hat{\mathbf{z}} \times [\vec{G}^{22}(\mathbf{r}, \mathbf{r}', \omega) - \vec{G}^{12}(\mathbf{r}, \mathbf{r}', \omega)] = 0, \quad (z=0),$$

$$\hat{\mathbf{z}} \times [\vec{G}^{32}(\mathbf{r}, \mathbf{r}', \omega) - \vec{G}^{22}(\mathbf{r}, \mathbf{r}', \omega)] = 0, \quad (z=d) \quad (18)$$

while the tangential components of the magnetic field give rise to surface currents, which may be written as

$$\begin{aligned} \hat{\mathbf{z}} \times [\nabla \times \vec{G}^{22}(\mathbf{r}, \mathbf{r}', \omega) - \nabla \times \vec{G}^{12}(\mathbf{r}, \mathbf{r}', \omega)] \\ = \frac{4\pi i\omega}{c^2} \vec{\sigma}_{1,2} \cdot \vec{G}^{12}(\mathbf{r}, \mathbf{r}', \omega), \quad (z=0), \\ \hat{\mathbf{z}} \times [\nabla \times \vec{G}^{32}(\mathbf{r}, \mathbf{r}', \omega) - \nabla \times \vec{G}^{22}(\mathbf{r}, \mathbf{r}', \omega)] \\ = \frac{4\pi i\omega}{c^2} \vec{\sigma}_{2,3} \cdot \vec{G}^{32}(\mathbf{r}, \mathbf{r}', \omega), \quad (z=d). \end{aligned} \quad (19)$$

The surface conductivities account for the finite absorption properties of the infinitely thin sheets in the material. The solution of the dyadic Green's function in the different regions may be written in terms of the reflection coefficients for the transverse (TE) electric waves and the transverse magnetic (TM) waves. For the system considered in Fig. 1, these are

$$\rho_E^+ = -\frac{2\pi\omega\sigma_{2,3}/(hc^2)}{1+2\pi\omega\sigma_{2,3}/(hc^2)}, \quad \rho_E^- = -\frac{2\pi\omega\sigma_{1,2}/(hc^2)}{1+2\pi\omega\sigma_{1,2}/(hc^2)},$$

$$\rho_B^+ = \frac{2\pi\sigma_{2,3}h/\omega}{1+2\pi\sigma_{2,3}h/\omega}, \quad \rho_B^- = \frac{2\pi\sigma_{1,2}h/\omega}{1+2\pi\sigma_{1,2}h/\omega}, \quad (20)$$

where (+) superscript defines the top plate and (-) superscript defines the bottom plate.²⁹

Making the definition $\Omega_{E,B} = 1 - \rho_{E,B}^+ \rho_{E,B}^- e^{2ihd}$, the scattering Green's function in region two is

$$\begin{aligned} \vec{G}_s^{22}(\mathbf{r}, \mathbf{r}') = & \frac{i\omega^2}{c^2} \int \frac{dk_\perp^2}{2\pi k_\perp^2 h} \left[\frac{\rho_E^-}{\Omega_E} \mathbf{M}(h) \mathbf{M}'(h) \right. \\ & + \frac{\rho_E^+ \rho_E^- e^{2ihd}}{\Omega_E} \mathbf{M}(h) \mathbf{M}'(-h) + \frac{\rho_E^+ \rho_E^- e^{2ihd}}{\Omega_E} \\ & \times \mathbf{M}(-h) \mathbf{M}'(h) + \frac{\rho_E^+ e^{2ihd}}{\Omega_E} \mathbf{M}(-h) \mathbf{M}'(-h) \\ & + \frac{\rho_B^-}{\Omega_B} \mathbf{N}(h) \mathbf{N}'(h) + \frac{\rho_B^+ \rho_B^- e^{2ihd}}{\Omega_B} \\ & \times \mathbf{N}(h) \mathbf{N}'(-h) + \frac{\rho_B^+ \rho_B^- e^{2ihd}}{\Omega_B} \mathbf{N}(-h) \mathbf{N}'(h) \\ & \left. + \frac{\rho_B^+ e^{2ihd}}{\Omega_B} \mathbf{N}(-h) \mathbf{N}'(-h) \right]. \quad (21) \end{aligned}$$

Similarly, the scattering Green's function in region one is

$$\begin{aligned} \vec{G}_s^{11}(\mathbf{r}, \mathbf{r}') = & \frac{i\omega^2}{c^2} \int \frac{dk_\perp^2}{2\pi k_\perp^2 h} \left\{ \left[\frac{\rho_E^- + (\rho_E^+ + 2\rho_E^- \rho_E^+) e^{2ihd}}{\Omega_E} \right] \right. \\ & \times \mathbf{M}(-h) \mathbf{M}'(-h) + \left[\frac{\rho_B^- + (\rho_B^+ - 2\rho_B^- \rho_B^+) e^{2ihd}}{\Omega_B} \right] \\ & \left. \times \mathbf{N}(-h) \mathbf{N}'(-h) \right\}. \quad (22) \end{aligned}$$

The other scattering Green's functions are found from the boundary conditions specified in Eqs. (18) and (19).

IV. FORCE BETWEEN N PARALLEL SHEETS

The Casimir force per unit area exerted on each planar sheet, see Fig. 1, is obtained by evaluating the zz component of the difference in the stress between the regions above and below that sheet. For example, the force on the bottom one is calculated by taking

$$T_b = [T_{zz}^{22}(z) - T_{zz}^{11}(z)]_{z=0}, \quad (23)$$

where T_b is the force per unit area on the bottom plate, T_{zz}^{22} is the zz component of the stress in region 2 given a fluctuating source in region 2, and T_{zz}^{11} is the zz component of the stress in region 1 given a fluctuating source in region 1. The force per unit area on the top plate is equal and opposite to that on the bottom one, i.e., $T_t = -T_b$. Combining the results in previous sections with Eq. (23) one obtains

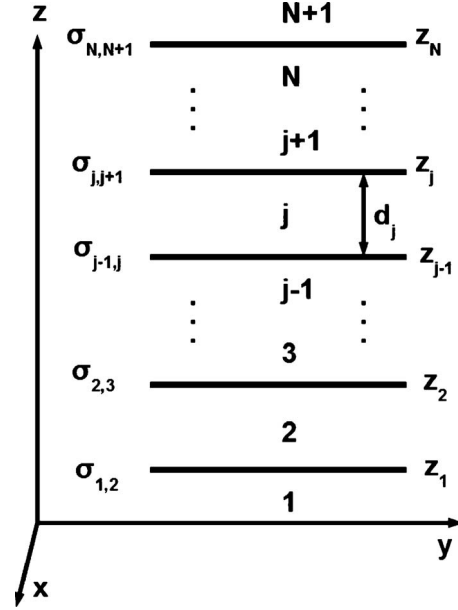


FIG. 2. N infinitely thin sheets located in free space and separated by distances d_j . The sheets extend in the x - y plane. Their conductivities and positions along the z axis are also shown.

$$\begin{aligned} T_b = & -\frac{ik_B T}{2\pi} \sum_{n=-\infty}^{\infty} \int_0^{\infty} h(i\omega_n) k_\perp dk_\perp \left\{ \left[\frac{e^{-2ih(i\omega_n)d}}{\rho_E^+(i\omega_n) \rho_E^-(i\omega_n)} - 1 \right]^{-1} \right. \\ & \left. + \left[\frac{e^{-2ih(i\omega_n)d}}{\rho_B^+(i\omega_n) \rho_B^-(i\omega_n)} - 1 \right]^{-1} \right\}, \quad (24) \end{aligned}$$

where $h(i\omega_n) = i\sqrt{(\omega_n/c)^2 + k_\perp^2}$. The expression for T_b can be used to calculate the temperature-dependent interaction between any two infinitely thin plates in the vacuum provided that the explicit conductivities are known. One notes that the largest contribution³⁰ of Eq. (24) comes from $\omega_n d/c \approx 1$. Therefore, when $\hbar c / (2\pi k_B T d) \gg 1$, the sum above is determined by the large n value terms and it can be transformed into an integral with differential $d\omega_n = 2\pi k_B T (dn)/\hbar$. For $T = 0$, such a representation is exact, but for $T \leq 300$ K, for example, d should not be larger than the order of micrometers. At distances comparable to the thermal quantum coherence wavelength $\lambda_T = \hbar c / (k_B T) \approx 7 \mu\text{m}$, classical thermal fluctuations become important and $\hbar c / (2\pi k_B T d) \gg 1$ is not valid any more. In this case, the $n=0$ and small n terms in the sum become important, and the $d\omega_n \sim dn$ transformation cannot be justified. Here, we will assume that we are in a regime where the integral representation is valid.

The result for the system of three layer/two sheet system can be used to obtain the force per unit area in the case of a stack of N parallel sheets. Consider the j th layer in Fig. 2. One realizes that the Casimir force results from the infinite optical reflecting and transmitting paths due to the scattering from all the sheets above and below layer j . This is described by the effective reflection from below $\rho_{j,E,B}^-$ and from above $\rho_{j,E,B}^+$ in layer j . Then combining Eq. (24) with the condition $\hbar c / (2\pi k_B T d) \gg 1$ and the integral representation that follows, the stress on the bottom sheet may be written as

$$T_{bj} = -\frac{i\hbar}{2\pi^2} \int_0^\infty k_\perp dk_\perp \int_0^\infty d\omega h(i\omega) \left\{ \left[\frac{e^{-2ih(i\omega)d_j}}{\rho_{Ej}^+(i\omega)\rho_{Ej}^-(i\omega)} - 1 \right]^{-1} + \left[\frac{e^{-2ih(i\omega)d_j}}{\rho_{Bj}^+(i\omega)\rho_{Bj}^-(i\omega)} - 1 \right]^{-1} \right\}. \quad (25)$$

Equations (24) and (25) are exactly the general Lifshitz formula found throughout the literature for various planar system, written in terms of the reflection coefficients. The temperature dependence does not appear explicitly in the force any more. It is accounted for indirectly through the temperature-dependent optical properties of the sheets. $\rho_{j,E,B}^\pm$ can be found via an iterative procedure using a simple recursion relation. Consider the three layers denoted as $(j-1), j, (j+1)$ by themselves. Due to the infinite optical paths they can be expressed as^{24,31}

$$\begin{aligned} \rho_{E,j-1,j,j+1} &= \rho_{E,j-1,j} + t_{E,j-1,j} \rho_{E,j,j+1} t_{E,j,j-1} e^{2ihd_j} \\ &\quad + t_{E,j-1,j} \rho_{E,j,j+1} t_{E,j,j-1} e^{4ihd_j} \rho_{E,j,j-1} \rho_{E,j,j+1} + \dots, \\ \rho_{E,j-1,j,j+1} &= \rho_{E,j-1,j} + t_{E,j-1,j} \rho_{E,j,j+1} t_{E,j,j-1} e^{2ihd_j} \\ &\quad \times \sum_{n=0}^{\infty} [\rho_{E,j-1,j} \rho_{E,j,j+1} e^{2ihd_j}]^n, \end{aligned} \quad (26)$$

where $\rho_{E,j-1,j}$ is a single sheet reflection coefficient from layer $j-1$ to layer j . Its expression is given in Eq. (20) with proper substitution of the indices. $t_{E,j-1,j}$ is the coefficient of transmission for a single sheet from layer $j-1$ to layer j . For the case of two thin sheets in the vacuum (or in a medium) one has $t_{E,j-1,j} = t_{E,j,j-1}$, $\rho_{E,j-1,j} = \rho_{E,j,j-1}$, and $1 + \rho_{E,j-1,j} = t_{E,j-1,j}$ whereupon one obtains

$$\rho_{E,j-1,j,j+1} = \frac{\rho_{E,j-1,j} + (\rho_{E,j,j+1} + 2\rho_{E,j,j+1}\rho_{E,j,j-1})e^{2ihd_j}}{1 - \rho_{E,j,j-1}\rho_{E,j,j+1}e^{2ihd_j}}. \quad (27)$$

Similarly, one finds the reflection coefficient for the TM modes given that $t_{B,j-1,j} = t_{B,j,j-1}$, $\rho_{B,j-1,j} = \rho_{B,j,j-1}$, and $1 - \rho_{B,j-1,j} = t_{B,j-1,j}$

$$\rho_{B,j-1,j,j+1} = \frac{\rho_{B,j-1,j} + (\rho_{B,j,j+1} - 2\rho_{B,j,j+1}\rho_{B,j,j-1})e^{2ihd_j}}{1 - \rho_{B,j,j-1}\rho_{B,j,j+1}e^{2ihd_j}}. \quad (28)$$

This provides a straightforward method for calculating the reflection coefficients in any vacuum layer in a stack of N parallel sheets. Suppose $j-1, j, j+1$ are a part of the system shown in Fig. 2. Starting from layer 1, one finds the reflection coefficients between the first and second layers using Eq. (20). Invoking Eqs. (27) and (28) recursively by treating the first two sheets as one, the reflection coefficient in the third layer is found. This is repeated until layer j is reached giving the effective reflection from below. A similar procedure is applied to find the reflection from all sheets from above layer j but starting from the top $N+1$ layer in Fig. 2.

As an example of the use of the recursion procedure, a four layered system will be considered, which corresponds to the bottom four layers of Fig. 2. Using Eqs. (27) and (28), the generalized reflection coefficients in layer 2 are expressed as

$$\begin{aligned} \rho_{E2}^+ &= \rho_{E234} = \frac{\rho_{E23} + (\rho_{E34} + 2\rho_{E23}\rho_{E34})e^{2ihd_3}}{1 - \rho_{E23}\rho_{E34}e^{2ihd_3}}, \\ \rho_{B2}^+ &= \rho_{B234} = \frac{\rho_{B23} + (\rho_{B34} - 2\rho_{B23}\rho_{B34})e^{2ihd_3}}{1 - \rho_{B23}\rho_{B34}e^{2ihd_3}}, \\ \rho_{E2}^- &= \rho_{E21}, \quad \rho_{B2}^- = \rho_{B21} \end{aligned} \quad (29)$$

Note that $\rho_{E,B,2}^-$ are actually $\rho_{E,B}^-$ from Eq. (20), since the system below layer 2 is the same as the one from Fig. 1. The reflection coefficients can be substituted in Eq. (25) yielding the Casimir force per unit area on the bottom plate in the four layer/three plate system.

It is important to realize that this formalism and the subsequent results can be applied in situations when the infinitely thin sheets are immersed in some media or above a substrate. Consider the cases when in each layer of Fig. 2 there is some substance characterized by dielectric $\epsilon_j(\omega)$ and magnetic $\mu_j(\omega)$ response properties. Then, the Casimir force can still be calculated using Eqs. (24) and (25), however, $h_j(\omega) \rightarrow \sqrt{\epsilon_j(\omega)\mu_j(\omega)\omega^2/c^2 - k_\perp^2}$ and the reflection coefficients have to correspond to the appropriate boundary conditions.^{30,32,33} Since the tangential components of \mathbf{E}_j are continuous and the tangential components of \mathbf{B}_j/μ_j give the current enclosed at each graphene surface, we find that for a single sheet

$$\rho_{Ej,j-1} = \frac{\left[\frac{h_j}{\mu_j} - \frac{h_{j-1}}{\mu_{j-1}} - \frac{4\pi\omega\sigma_{j,j-1}}{c^2} \right]}{\left[\frac{h_j}{\mu_j} + \frac{h_{j-1}}{\mu_{j-1}} + \frac{4\pi\omega\sigma_{j,j-1}}{c^2} \right]}, \quad (30)$$

$$\rho_{Bj,j-1} = \frac{\left[\epsilon_{j-1}h_j - \epsilon_j h_{j-1} + \frac{4\pi\sigma_{j,j-1}h_j h_{j-1}}{\omega} \right]}{\left[\epsilon_{j-1}h_j + \epsilon_j h_{j-1} + \frac{4\pi\sigma_{j,j-1}h_j h_{j-1}}{\omega} \right]}. \quad (31)$$

Using the iteration described above, one can calculate the Casimir force in situations when the infinitely thin sheets are above substrates and/or immersed in some medium.

V. CASIMIR INTERACTION BETWEEN GRAPHENES

Before the graphene planes are considered, it is useful to calculate the interaction for the limit of infinitely conducting planar sheets. In that case, the conductivity becomes $\sigma \rightarrow \infty$ yielding $\rho_{Ej}^\pm \rightarrow -1$ and $\rho_{Bj}^\pm \rightarrow 1$. Thus using Eq. (25) we recover the well-known result¹ for the magnitude of the attraction between two parallel perfectly conducting plates separated by a distance d

$$|T_0| = \frac{\hbar c \pi^2}{240d^4}. \quad (32)$$

A. Universal conductivity

Further, we apply the results for infinitely thin sheets obtained in Sec. IV to calculate the Casimir force between two graphenes. Researchers in the past have considered graphene as an infinitely thin sheet and have shown that this is a reasonable approximation for distances greater than a few times the interlayer graphite separation.^{15,16} The emphasis now is to specify the graphene conductivity. It has been predicted^{34,35} and found experimentally,³⁶ that over a relatively wide range of photon energies (up to 3 eV), the graphene conductivity is approximately constant given by the value of $\sigma_0 = e^2 / (4\hbar)$. This peculiar effect is closely related to the energy band structure of graphene, as shown in the Appendix.

Given a constant conductivity σ_0 for two parallel sheets separated by a distance d , Eq. (25) may be written in the following form:

$$|T_g| = \frac{3\hbar c}{16\pi^2 d^4} \sum_{n=1}^{\infty} \left(\frac{1}{n^4} \right) [F(\sigma_0, n) + G(\sigma_0, n)],$$

$$F(\sigma_0, n) = \frac{c}{2\pi\sigma_0} \beta \left(\frac{2\pi\sigma_0/c}{1 + 2\pi\sigma_0/c}, 2n + 1, -1 \right),$$

$$G(\sigma_0, n) = \frac{2\pi\sigma_0}{c} \left(\frac{1}{2n - 1} \left[1 - \left(\frac{2\pi\sigma_0/c}{1 + 2\pi\sigma_0/c} \right)^{(2n-1)} \right] \right) \tag{33}$$

where

$$\beta(x, a, b) = \int_0^x t^{a-1} (1-t)^{b-1} dt \tag{34}$$

is the incomplete beta function.³⁷

For graphene, however, $2\pi\sigma_0/c \ll 1$. Then Eq. (33) is approximated by taking the first term in the sum, which reduces to

$$|T_g| \approx \frac{3\hbar c}{8\pi^2 d^4} \left[1 - \frac{c}{2\pi\sigma_0} \ln(1 + 2\pi\sigma_0/c) \right]. \tag{35}$$

Further expansion of the ln function and inserting σ_0 gives

$$|T_g| \approx \frac{3\hbar c}{16\pi^2 d^4} \frac{2\pi\sigma_0}{c} = \frac{3e^2}{32\pi d^4}, \tag{36}$$

where Eq. (36) is the first term of a perturbative expansion whereupon σ_0 is small compared to the speed of light. Thus the leading term in the force does not depend explicitly on the Planck's constant and speed of light any more. This is a remarkable result originating from the particular value of the graphene conductivity. We note that the approximate result from Eq. (35) is fairly accurate since it differs by less than 2% from the numerical integration of the exact result Eq. (25).

It is also interesting to see the similarities and differences between T_g and T_0 . In particular, the distance dependence of the Casimir force is the same as the one between two perfect conductors. This is in marked contrast to previous results within the hydrodynamic approximation for two planes with

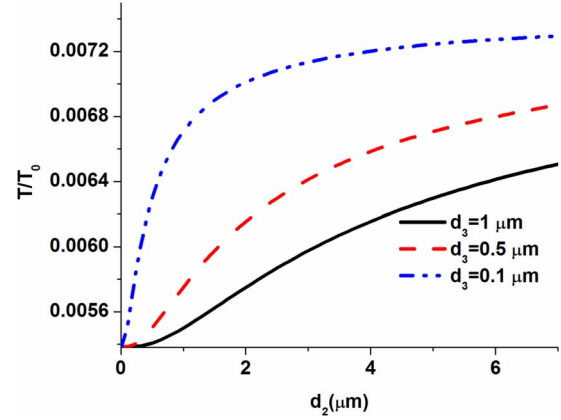


FIG. 3. (Color online) Casimir force per unit area between two adjacent graphenes in a three layer system [d_2 and d_3 are defined according to Fig. 2].

dielectric properties described by the plasma model.¹⁵ After comparing the values of the stress, one obtains $T_g/T_0 \approx 0.00538$. Thus the graphene Casimir interaction is much smaller in magnitude than the interaction between perfect conductors. This is directly related to the transparency of the graphene system, reflected in its small constant conductivity value.

The interaction between a perfectly conducting plate and graphene can also be calculated via Eq. (25). In this case the force is much larger as compared to the one between two graphenes. Given the constant σ_0 for graphene and $\sigma \rightarrow \infty$ for a perfect metal, one finds $T/T_0 \approx 0.025$.

The general formula from Eq. (25) allows one to consider the Casimir interaction in a system with more than two parallel graphenes. Here we study the force within a three plane system. The interaction between two adjacent graphene planes will now, not only depend on their distance d_2 , but will also depend on the distance of the third plane d_3 —Fig. 2.

Figure 3 shows the Casimir force per unit area between the two graphene sheets when the third one is at a certain separation d_3 . We find that when $d_3 \gg d_2$, the force between two graphenes separated at d_2 is recovered— $|T/T_0| \rightarrow |T_g/T|$. However, for $d_3 \ll d_2$, we obtain $|T/T_0| \approx 2 \ln 2 |T_g/T|$ indicating that when the third graphene is brought very close, its contribution to the reflection coefficients is stronger resulting in a larger effective force.

B. Other models for the conductivity

The low-energy graphene band structure has been very successful in explaining experimentally observed properties at various temperatures.^{34,35} Since the Casimir interaction at larger separations is determined by that regime (corresponding to optical excitations less than 3 eV), one concludes that its qualitative features cannot be an exception. Nevertheless, as the graphenes are brought closer, the presence of the higher energy bands besides the ones closest to the Fermi level also needs to be considered.

Direct measurements of the graphene conductivity have been done at photonic energies below 3 eV so far.³⁶ Experi-

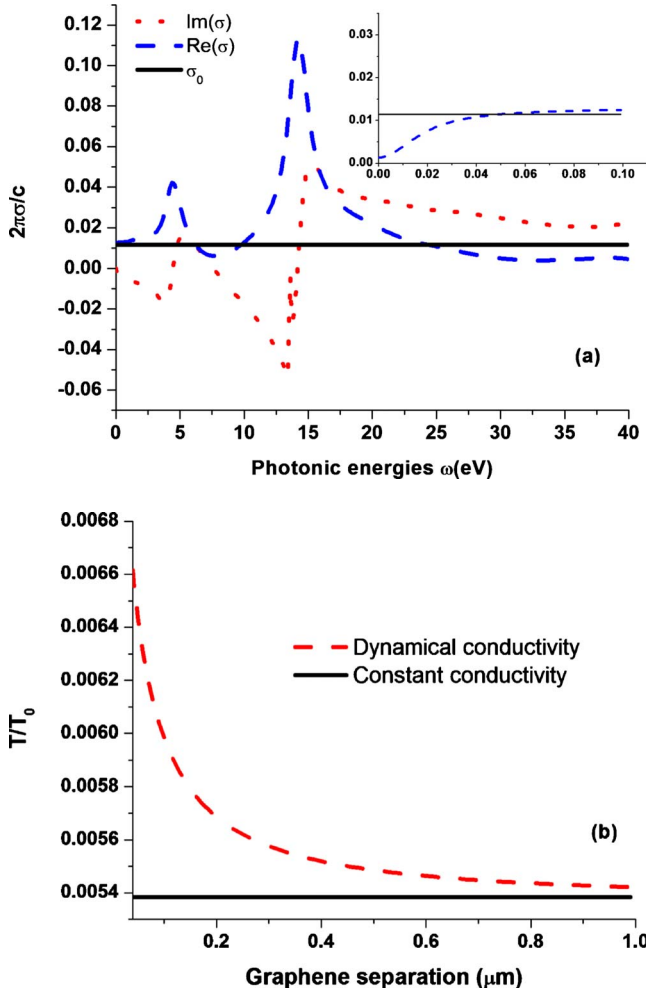


FIG. 4. (Color online) a) Re and Im parts of the dynamical conductivity for in-plane graphite. The universal graphene conductivity σ_0 is also shown. The insert displays the infrared regime. (b) The Casimir force between graphenes as a function of distance with constant and dynamical conductivities. The force is normalized to the one for perfect conductors.

ments appropriate for higher regimes have not been currently reported. At the same time, investigating σ theoretically is one of the issues at the forefront of graphene science. Recent *ab initio* calculations indicate that the in-plane optical properties of graphite and graphene are very similar over a wide range of frequencies.^{38,39} Experimentally it was also reported that the optical conductivity of graphite per graphene sheet is very close to the universal σ_0 value of an isolated graphene⁴⁰ for low optical frequencies. Thus a viable approach for further investigating the Casimir force between graphenes is to use the in-plane optical data of graphite and transpose it to graphene.

Results from *ab initio* calculations for graphite have been mapped to a series of Lorentz oscillators with a Drude term, whose parameters fit previous graphite measurements⁴¹ between 0.1 and 40 eV. A plot of the in-plane conductivity as a function of photon energies is shown in Fig. 4(a). We note that in the infrared spectrum σ of the two systems are different—insert of Fig. 4(a). For graphite, the conductivity exhibits a Drude-type behavior from intraband transitions

while the conductivity for graphene stays constant. This has also been observed experimentally⁴⁰ and it can be explained in terms of the electronic structures of the two systems. The onset of the Drude-type term in graphite is related to the splitting of the energy bands and their becoming slightly parabolic due to the interlayer interaction while the constant σ_0 in graphene originates from cancellations occurring between the intraband and interband transitions due to the linear in k energy bands as shown in the Appendix. Thus for the calculations here, we modify the fitted model⁴¹ for photon energies in the infrared region (below 0.05 eV) by requiring $\sigma = \sigma_0$ [insert of Fig. 4(a)].

For larger photonic energies, the in-plane graphite conductivity is mainly determined by the single-graphene properties. The Lorentz oscillator model shows that $\text{Re}(\sigma)$ stays relatively constant in the low optical regime (up to 3 eV), which means that the universal graphene conductivity has not been affected significantly by the presence of the other graphene layers. This is in agreement with previous experimental findings.⁴⁰ Also, the two peaks in $\text{Re}(\sigma)$ that appear around 5 and 15 eV are related to $\pi - \pi^*$ and $\sigma - \sigma^*$ electron transitions for an isolated graphene,^{38,39} respectively. A sizeable imaginary part of the conductivity also appears after 3 eV.

Using this model, the force between two parallel graphenes is found via Eq. (25). We show the normalized to perfect conductors force per unit area as a function of distance in Fig. 4(b), both when σ is taken from the data of graphite and when $\sigma = \sigma_0$ over the entire range of frequencies. The plot shows that at longer distances the force approaches the one given with a constant conductivity, but at shorter distances higher photon frequency modes contribute to an increasingly larger force. Note that the force itself is always real, even with a complex conductivity as shown in Fig. 4(a). This is directly related to the requirement that Kramers-Kronig relations be satisfied, which implies real contributions to the force.

C. Graphenes and other materials

It is interesting to consider the graphene interaction when other materials can contribute to their mutual force. Many experimental settings involve graphenes immersed in some medium or above a substrate. For example, new methods of synthesis have been demonstrated with graphene dispersion and exfoliation in inorganic solvents, ionic liquids, or some other environment.⁴² Other situations may involve device construction or handling of graphene on top of substrates, such as SiC, SiO₂, Ni, etc.⁴³

We apply the formalism we have developed to investigate how the Casimir force depends on the dielectric response properties of other materials. The force in a two and three graphene setting for two cases is considered: above a substrate and immersed in some medium. In many experiments, the substrate is usually of metallic type,⁴³ thus we model its dielectric function using $\epsilon_s(\omega) = 1 - \frac{\Omega_{ps}^2}{\omega^2 + i\omega\Gamma_s}$, where Ω_{ps} is the plasma frequency and Γ_s is the decay rate. On the other hand, the medium where graphenes are submerged usually has a dielectric nature. Therefore, we use the Lorentz oscil-

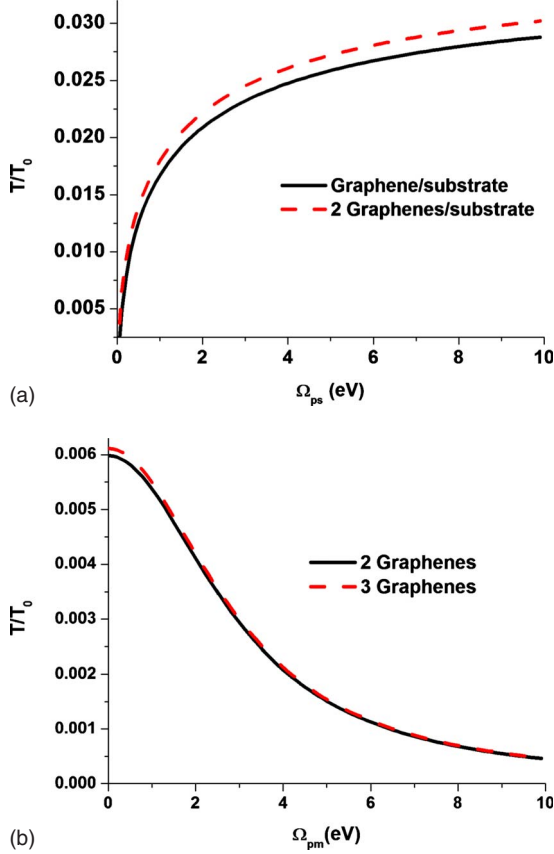


FIG. 5. (Color online) (a) Casimir force per unit area between graphene and a substrate (solid black) and between two graphenes and a substrate (dashed red) as a function of the substrate plasma frequency. (b) Casimir force per unit area between two adjacent graphenes in a two (solid black) and three (dashed red) layer system in a medium as a function of the Lorentz oscillator strength for the medium's dielectric function. Also, $d=d_2=d_3=0.1 \mu\text{m}$, $\omega_0=3 \text{ eV}$, and $\Gamma_3=\Gamma_m=0.1 \text{ eV}$.

lator model for the dielectric function $\epsilon_m(\omega)=1-\frac{\Omega_{pm}^2}{\omega^2-\omega_0^2+i\omega\Gamma_m}$, where Ω_{pm} is the strength of the oscillator, ω_0 is its position, and Γ_m is the decay rate.

Figure 5(a) shows the force between a single graphene and the substrate and between graphene and the substrate when a second graphene is above the first one as a function of the plasma frequency. The interaction is strongly enhanced by the substrate as Ω_{ps} increases. For very large plasma frequency, the results approach that of an ideal metal. Figure 5(b) shows the force between two graphenes in a two and three layer system as a function of strength of the Lorentz oscillator. The medium has the opposite effect as compared to the substrate. As Ω_{pm} increases, the graphene force is strongly suppressed, thus the interaction is screened. This is also partly due to the large transparency of the layers themselves. In fact, for larger Ω_{pm} , the mutual Casimir force is determined by the adjacent graphenes while the role of the third one is small.

VI. CONCLUSION

We have studied the Casimir force between parallel, infinitely thin sheets in free space. The particular absorption

optical properties are taken into account via the conductivities of each sheet. The derived expressions rely on generalized Fresnel reflection coefficients obtained with an iterative procedure. This is especially convenient since it is applicable to a system of N sheets. The theory is applied to the case of graphene/graphene Casimir interaction in order to study how this fundamental effect depends on the graphene optical response and the distance separation. The graphene conductivity is described with a model based on the low energy band structure first. In this case, we find that the Casimir force obeys the same distance dependence as the force between two perfect conductors, but it is much smaller in magnitude due to the graphene transparency. These results are directly related to the existence of a constant graphene conductivity $\sigma_0=e^2/(4\hbar)$ over the optical range of photon energies. This universal value translates into a mutual Casimir force that depends only on the electron charge and the distance.

The graphene conductivity is also calculated using a model based on *ab initio* calculations and appropriate for in-plane graphite optical data. For graphite, σ however, has to be modified in the infrared photon energy region in order to reflect experimental and theoretical results for the existence of a constant graphene conductivity. This is important for the interaction in the limit of large separations. In addition, the Casimir force is investigated when the graphene system is positioned above a substrate or immersed in medium as a function of the environmental material dielectric response characteristics.

Finally, we comment that the graphene conductivity might be influenced by other factors such as electron-phonon interaction, electron correlation effects and the presence of exciton. Efforts to understand and quantify these effects theoretically have just begun.⁴⁴ Experimental research is also needed to validate such studies. Thus it would be interesting to explore in the future other models for the conductivity of graphene in relation to their mutual Casimir interaction.

ACKNOWLEDGMENT

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APPENDIX: CONDUCTIVITY MODEL

The conductivity of graphene can be modeled using the low-energy electron excitations, which obey a linear momentum energy-dispersion relation $\epsilon=\pm v_F k$, where $v_F\approx c/300$, and k is the magnitude of the two-dimensional wave vector.¹⁶ Within the Kubo formalism, the conductivity is expressed^{35,45} using

$$\sigma(\omega,\Gamma)=\sigma_{intra}(\omega,\Gamma)+\sigma_{inter}(\omega,\Gamma),$$

$$\sigma_{intra}(\omega,\Gamma)=-\frac{ie^2}{\pi\hbar^2(\omega+i\Gamma)}\int_0^\infty\epsilon d\epsilon\left[\frac{\partial f(\epsilon)}{\partial\epsilon}-\frac{\partial f(-\epsilon)}{\partial\epsilon}\right],$$

$$\sigma_{inter}(\omega, \Gamma) = \frac{ie^2(\omega + i\Gamma)}{\pi\hbar^2} \int_0^\infty d\epsilon \frac{f(-\epsilon) - f(\epsilon)}{(\omega + i\Gamma)^2 - 4(\epsilon/\hbar)^2}, \quad (\text{A1})$$

where $f(\epsilon) = 1/[\exp(\epsilon/k_B T) + 1]$ is the Fermi-Dirac distribution function and Γ is a damping parameter which accounts for physical processes contributing to broadening of the optical spectrum. $\sigma_{intra}(\omega, \Gamma)$ is the intraband contribution to the conductivity which is found to be

$$\sigma_{intra}(\omega, \Gamma) = \frac{i2e^2 k_B T \ln(2)}{\pi\hbar(\omega + i\Gamma)} \quad (\text{A2})$$

while the interband contribution to the conductivity is calculated as

$$\sigma_{inter}(\omega, \Gamma) = -\frac{ie^2(\omega + i\Gamma)}{8\pi k_B T} \int_0^\infty dx \frac{\tanh(x)}{x^2 - (\hbar(\omega + i\Gamma)/4k_B T)^2}. \quad (\text{A3})$$

In the small temperature limit, Eqs. (A2) and (A3) result in σ being a constant— $\sigma_0 = e^2/(4\hbar)$. Our sample plot of $\sigma(i\omega, \Gamma)/\sigma_0$ vs ω , however, shows that even at higher temperatures, the conductivity does not differ much from the

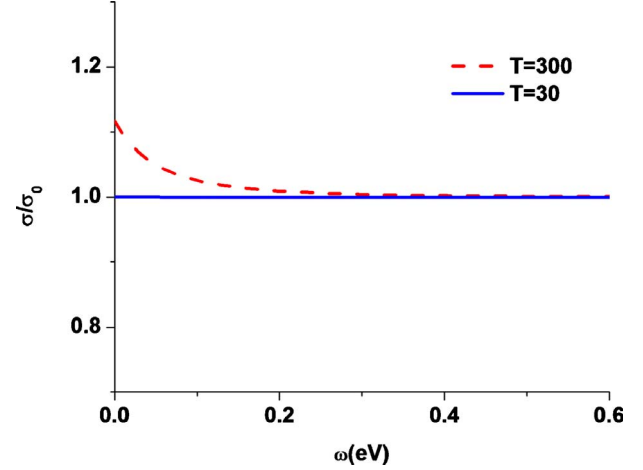


FIG. 6. (Color online) Graphene conductivity $\sigma(i\omega)$ in units of $\sigma_0 = e^2/(4\hbar)$ vs frequency is given at two temperatures, $T=300$ K and $T=30$ K. The scattering rate is $\Gamma=0.1$ eV.

universal constant value, Fig. 6. Our calculations also show that the temperature entering through the conductivity has little effect on the Casimir force. Indeed, the force at 300 K differs by less than 1% as compared to the one for 0 K.

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²⁹Notice that the coefficients in Eq. (20) correspond to those previously obtained for infinitely sheets. For example, the reflection coefficients in Eq. (2.14) and (2.15) from Ref. 17 written in terms of the parameters q and p yield Eq. (20) after the substitution $2\pi\omega\sigma/c^2 = iq$ and $h = p$.

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